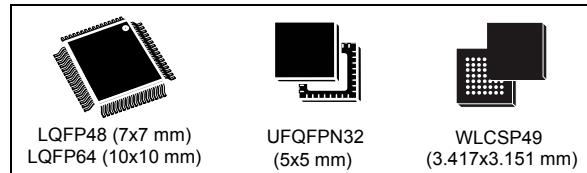


ARM® Cortex®-M4 32-bit MCU+FPU, up to 64 KB Flash,
16 KB SRAM, ADC, DAC, USB, CAN, COMP, Op-Amp, 2.0 - 3.6 V

Datasheet - production data

Features

- Core: ARM® 32-bit Cortex®-M4 CPU with FPU (72 MHz max.), single-cycle multiplication and HW division, DSP instruction
- Memories
 - 32 to 64 Kbytes of Flash memory
 - 16 Kbytes of SRAM on data bus
- CRC calculation unit
- Reset and power management
 - V_{DD} , V_{DDA} voltage range: 2.0 to 3.6 V
 - Power-on/Power down reset (POR/PDR)
 - Programmable voltage detector (PVD)
 - Low-power: Sleep, Stop, and Standby
 - V_{BAT} supply for RTC and backup registers
- Clock management
 - 4 to 32 MHz crystal oscillator
 - 32 kHz oscillator for RTC with calibration
 - Internal 8 MHz RC with x 16 PLL option
 - Internal 40 kHz oscillator
- Up to 51 fast I/O ports, all mappable on external interrupt vectors, several 5 V-tolerant
- Interconnect matrix
- 7-channel DMA controller supporting timers, ADCs, SPIs, I²Cs, USARTs and DAC
- 1 × ADC 0.20 μ s (up to 15 channels) with selectable resolution of 12/10/8/6 bits, 0 to 3.6 V conversion range, single ended/differential mode, separate analog supply from 2.0 to 3.6 V
- Temperature sensor
- 1 x 12-bit DAC channel with analog supply from 2.4 to 3.6 V
- Three fast rail-to-rail analog comparators with analog supply from 2.0 to 3.6 V
- 1 x operational amplifier that can be used in PGA mode, all terminal accessible with analog supply from 2.4 to 3.6 V



- Up to 18 capacitive sensing channels supporting touchkey, linear and rotary sensors
- Up to 9 timers
 - One 32-bit timer with up to 4 IC/OC/PWM or pulse counter and quadrature (incremental) encoder input
 - One 16-bit 6-channel advanced-control timer, with up to 6 PWM channels, deadtime generation and emergency stop
 - Three 16-bit timers with IC/OC/OCN or PWM, deadtime gen. and emergency stop
 - One 16-bit basic timer to drive the DAC
 - 2 watchdog timers (independent, window)
 - SysTick timer: 24-bit downcounter
- Calendar RTC with alarm, periodic wakeup from Stop/Standby
- Communication interfaces
 - Three I2Cs with 20 mA current sink to support Fast mode plus
 - Up to 3 USARTs, 1 with ISO 7816 I/F, autobaudrate detect and Dual clock domain
 - Up to two SPIs with multiplexed full duplex I2S
 - USB 2.0 full-speed interface
 - 1 x CAN interface (2.0B Active)
 - Infrared transmitter
- Serial wire debug (SWD), JTAG
- 96-bit unique ID

Reference	Part number
STM32F302x6	STM32F302R6, STM32F302C6, STM32F302K6
STM32F302x8	STM32F302R8, STM32F302C8, STM32F302K8

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